Silicon N-Channel Junction FET

HITACHI

Application

VHF Amplifier, Mixer, Local oscillator

Outline





Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

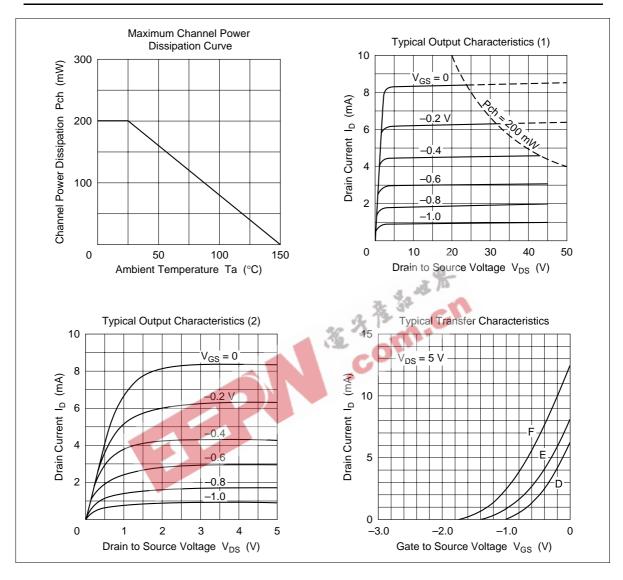
Item	Symbol	Ratings	Unit
Gate to drain voltage	$V_{\sf GDO}$	-30	V
Gate to source voltage	V _{GSS}	– 1	V
Gate current	I _G	10	mA
Drain current	I _D	20	mA
Channel power dissipation	Pch	200	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

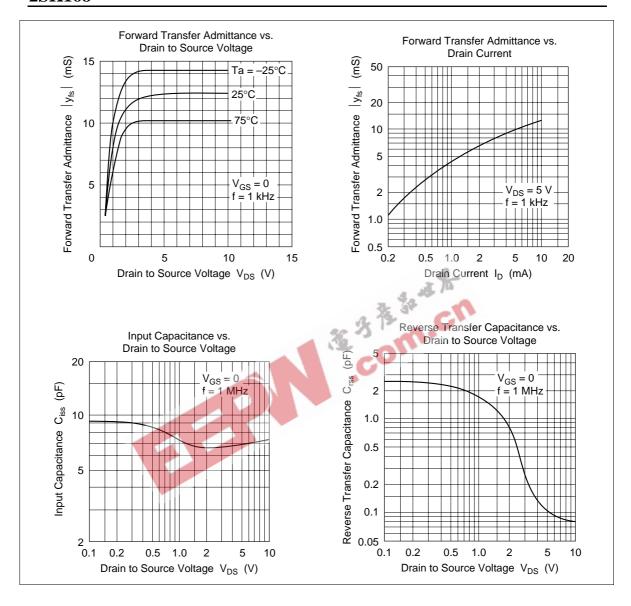
Electrical Characteristics ($Ta = 25^{\circ}C$)

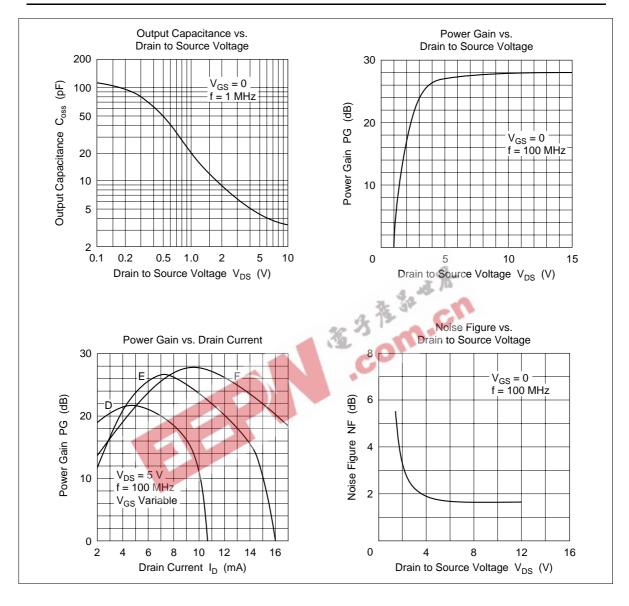
Electrical Characteristics (Ta = 25°C)				A A The		
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Gate to drain breakdown voltage	$V_{(BR)GDO}$	-30	- 3	23 1	V	$I_{\rm G} = -100 \mu \text{A}, I_{\rm S} = 0$
Gate cutoff current	I _{GSS}	$\dashv \blacksquare$	1-1	-10	nA	$V_{GS} = -0.5 \text{ V}, V_{DS} = 0$
Drain current	l _{DSS} *1	4		20	mA	$V_{DS} = 5 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	7	_	-3.0	V	$V_{DS} = 5 \text{ V}, I_{D} = 10 \mu\text{A}$
Forward transfer admittance	y _{fs}	8	10	_	mS	$V_{DS} = 5 \text{ V}, V_{GS} = 0, f = 1 \text{ kHz}$
Input capacitance	Ciss	_	6.8	_	pF	$V_{DS} = 5 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$
Reverse transfer capacitance	Crss	_	0.1	_	pF	$V_{DS} = 5 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$
Power gain	PG	_	27	_	dB	$V_{DS} = 5 \text{ V}, V_{GS} = 0,$ f = 100 MHz
Noise figure	NF	_	1.7	_	dB	$V_{DS} = 5 \text{ V}, V_{GS} = 0,$ f = 100 MHz

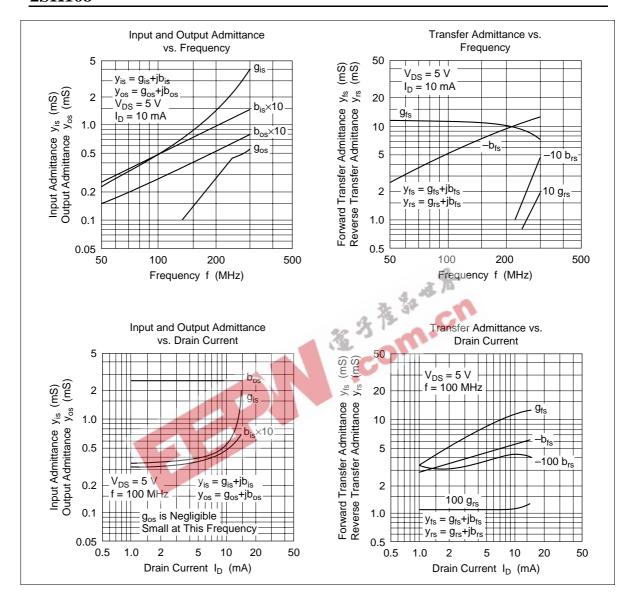
Note: 1. The 2SK168 is grouped by I_{DSS} as follows.

D	E	F
4 to 8	6 to 12	10 to 20









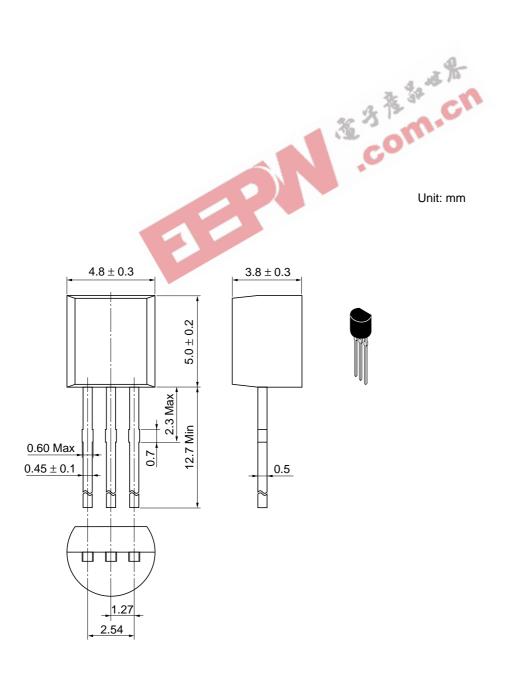
Power Gain and Noise Figure Test Circuit

$$\begin{array}{c|c} \text{Shield} \\ 5.4 \\ \hline \\ \text{SG Output} \\ \text{Impedance} \\ \\ \text{M} \end{array} \\ \begin{array}{c|c} \text{Shield} \\ \hline \\ \text{SC}_1 \neq \\ \\ \text{S.G.} \\ \\ \end{array} \\ \begin{array}{c|c} \text{Shield} \\ \hline \\ \text{SDUJT.} \\ \hline \\ \text{C}_2 \neq \\ \\ \text{SL}_2 \\ \\ \text{4,700} \\ \\ \text{1,000} \\ \\ \text{III} \\ \\ \text{M} \end{array} \\ \begin{array}{c|c} \text{OV.V} \\ \\ \text{Impedance} \\ \\ \text{VDD} \\ \end{array} \\ \begin{array}{c|c} \text{C}_1 \neq \\ \\ \text{S.G.} \\ \\ \text{M} \end{array} \\ \begin{array}{c|c} \text{DUJT.} \\ \\ \text{C}_2 \neq \\ \\ \text{M} \\ \\ \text{M} \end{array} \\ \begin{array}{c|c} \text{MICRITICAL STATES } \\ \\ \text{C} : pF \end{array}$$

 $\rm C_1,\, C_2$: 0 to 30 pF Variable Air $\rm L_1$: 3.5 T 1 mm φ Copper Ribbon, Tin plated 10 mm Inside dia. L2: 4.5 T 1 mm

Copper Ribbon, Tin plated 10 mm Inside dia.





Hitachi Code	TO-92 (2)
JEDEC	Conforms
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Weight (reference value)	0.25 g

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Semiconductor & Integrated Circuits. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

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For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose,CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223 Hitachi Europe GmbH Electronic components Group Dornacher Stra§e 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0

Fax: <49> (89) 9 29 30 00 Hitachi Europe Ltd. Electronic Components Group.

Whitebrook Park

Lower Cookham Road

Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100 Fax: 535-1533

Hitachi Asia Ltd

Taipei Branch Office 3F, Hung Kuo Building. No.167 Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218 Fax: <852> (2) 730 0281 Telex: 40815 HITEC HX

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